

Performance and Geant4 simulation of particle detection with low-cost CMOS technology

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Imaging sensors

Complementary Metal Oxide Semiconductors (CMOS): used to detect particles: gamma rays, electrons, alphas, etc.

Examples:

- discrimination between alpha and non-alpha particles by identifying ionization events
- photon imaging using fluorescence X-rays and gamma rays



physi.uni-heidelberg.de/~sma/teaching/ParticleDetectors2/



Experimental Setup





OmniVision OV5647 sensor





OmniVision OV5647 sensor

For stability in data acquisition fixed settings:

- **Shutter speed** = 0.5 s (frame exposure time)
- Image resolution = 2592x1944\$ pixels (5 Mp) = maximum
- Analog gain = 8, max stable response without image distortion
- **Digital gain** = 1, no artificial gain
- White balance = 1, no color correction



Image capture:

- **10-bit Bayer format:** 3 color matrices R(25%) G(50%) B(25%)
- Measure intensity: add matrices



Radioactive sources

Beta emitters:

- Sr90: electrons E_{max}=0.546 MeV -> Y90: electrons E_{max}=2.28 MeV Activity: 3174 Bq
- Cs137: electrons E=0.514 MeV -> Ba-137m: 0.662 MeV photons Activity: 7982 Bq





Geant4 simulation



Simulate 0.5 s:

- Sr90: 1587 events
- Cs137: 3991 events
- Geant4 gives: energy deposited in pixel matrix

Further steps:

- Convert to electrons in Si using 3.6 eV factor (energy to generate e-/hole pair)
- Apply Interpixel Capacitance (IPC)
- Convert electron number into ADC counts:

FWC (full well capacity) = $4300 e^{-} = 1023 ADC$ Minimum = $5 e^{-} = 1 ADC$



Inter Pixel Capacitance (IPC)

Crosstalk: fringing fields from capacitors in each pixel cause the voltage readings in a pixel to depend on the charges in neighboring pixels



https://doi.org/10.1364/AO.51.002877

Two-dimensional symmetry model



Standard value of ξ =0.075

PUCP Background subtraction by pixel



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Pixel Clusters

Using **OpenCV libraries** to find clusters:



For each cluster calculate:

- **size** (i.e. number of pixels),
- mean ADC,
- maximum ADC
- total ADC number





Results

Data/Simulation comparison at pixel level





Results

Data/Simulation comparison at cluster level





Results

Data/Simulation comparison: variables correlation at cluster level



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Source distance dependence





Source comparison



Similar distribution between radioactive sources



Conclusions

- Experimental setup for data acquisition with CMOS camera and Raspberry Pi.
- Camera settings for stable and sensitive measurements.
- Background reduction procedure: from 99% pixels to >0.1% signal pixels.
- Implemented detailed Geant4 simulation, including energy to ADC conversion and IPC crosstalk.
- Good agreement (within 1 sigma) between experiment and simulation at pixel, cluster and correlation level.
- Experimental data and simulation follow an inverse square distance distribution.
- It is not possible to distinguish between radioactive sources.



Thanks!

Grupo de Altas Energías (desde 2002)

Profesores Investigadores:







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Dr. Joel Jones Dr. Alberto Gago Líder del Grupo

Estudiantes:

- Doctorado: 9
- Maestría: 4
- Egresados: 4
- Pregrado: 9

Graduados: 1 doctorado, 26 maestría, 5 licenciatura











Teoría/fenomenología

- Oscilaciones de neutrinos
- Neutrinos pesados
- Supersimetría
- Nueva física en colisionadores
- Astropartículas

Experimentos Internacionales

- **MINERvA** (2006)
- ALICE (2009)
- DUNE (2017)
- SWGO (2019)

Desarrollo de detectores

- SiPM, webcam, Arduino, Raspberry Pi
- Muones y fuentes radioactivas

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https://investigacion.pucp.edu.pe/grupos/hep/

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Source comparison

